

**Dated:** \_\_\_\_\_

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Examiner: Not Yet Assigned

## {W:\20046\0200501us0\00122000.DOC { 0000 0000 0000 0000 0000 0000 0000 0000 0000 0000 0000 0000 0000 }

A concise explanation of relevance of Citations CC and CD listed on form PTO/SB/08 is attached.

In accordance with 37 CFR 1.97(g), the filing of this Information Disclosure Statement shall not be construed to mean that a search has been made or that no other material information as defined in 37 CFR 1.56(a) exists. In accordance with 37 CFR 1.97(h), the filing of this Information Disclosure statement shall not be construed to be an admission that any patent, publication or other information referred to therein is “prior art” for this invention unless specifically designated as such.

It is submitted that the Information Disclosure Statement is in compliance with 37 CFR 1.98 and the Examiner is respectfully requested to consider the listed documents.

The Commissioner is authorized to charge any deficiency of up to \$300.00 or credit any excess in this fee to Deposit Account No. 04-0100.

Dated: January 23, 2004

Respectfully submitted,

By John FLYNN BARRISAN  
REG. No. 53,970

Laura C. Brutman

Registration No.: 38,395

DARBY & DARBY P.C.

P.O. Box 5257

New York, New York 10150-5257

(212) 527-7700

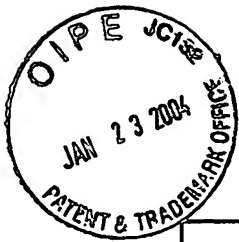
(212) 753-6237 (Fax)

Attorneys/Agents For Applicant

## Concise Explanation

Citation No. CC - pages 1415-1423 describes the general structure and operation of temperature-compensated reference diodes.

Citation No. CD - pages 555-560 describes different means for generating a reference voltage. In particular, reference voltage sources including so called zener diodes are described.



Under the Paperwork Reduction Act of 1995, no persons are required to respond to a collection of information unless it contains a valid OMB control number.

<b>Substitute for form 1449A/B/PTO</b>  <b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b>  (Use as many sheets as necessary)				<b>Complete if Known</b>	
				Application Number	10/714,536
				Filing Date	November 13, 2003
				First Named Inventor	Ralf Brederlow
				Art Unit	N/A
				Examiner Name	Not Yet Assigned
				Attorney Docket Number	20046/0200501-USO
Sheet	1	of	1		

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. <sup>1</sup>	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code <sup>2</sup> (if known)			
	AA	US-6,455,873-B1	09-24-2002	Lonergan	

FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No. <sup>1</sup>	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T <sup>3</sup>
		Country Code <sup>3</sup> -Number <sup>4</sup> -Kind Code <sup>5</sup> (if known)				
	BA	WO-01/01452-A2	01-04-2001	Jackson, Thomas et al.		

\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. <sup>1</sup> Applicant's unique citation designation number (optional). <sup>2</sup> See Kinds Codes of USPTO Patent Documents at [www.uspto.gov](http://www.uspto.gov) or MPEP 901.04. <sup>3</sup> Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). <sup>4</sup> For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. <sup>5</sup> Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. <sup>6</sup> Applicant is to place a check mark here if English language Translation is attached.

NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>2</sup>
	CA	C.D. Dimitrakopoulos, et al.; "Organic thin-film transistors: A review of recent advances"; IBM J. Res. & Dev., vol. 45 no. 1, January 2001; pages 11-27	
	CB	P.V. Necliudov, et al.; "Modeling of organic thin film transistors of different designs"; Journal of Applied Physics, vol. 88, number 11, 1 December 2000, pages 6594-6597.	
	CC	D. Nuhmann; "Das grosse Werkbuch Elektronik ist 20 Jahre alt", vol. 2, 1998, Franzis ' Verlag Poing, ISBN 3 7723-6547-7, pages 1415-1423	
	CD	U. Tietze, C. Schenk "Halbeiterschaltungstechnik", Springer-Verlag, Berlin, 1993, pages 555-560.	

\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

<sup>1</sup> Applicant's unique citation designation number (optional). <sup>2</sup> Applicant is to place a check mark here if English language Translation is attached.

Examiner Signature		Date Considered	
-----------------------	--	--------------------	--

Attorney Docket No.: 20046/0200501-US0

# Certificate of Express Mailing Under 37 CFR 1.10

I hereby certify that this correspondence is being deposited with the United States Postal Service as Express Mail, Airbill No. \_\_\_\_\_ in an envelope addressed to:

2994069389-US

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

on January 23, 2004  
Date

*Leck*

Signature

Typed or printed name of person signing

**Note:** Each paper must have its own certificate of mailing, or this certificate must identify each submitted paper.

Information Disclosure Statement  
PTO/SB/08a with five documents  
Concise explanation  
Return Receipt Postcard